

## N-Channel Power MOSFET

## **Description**

The XR46000 is a silicon N-channel enhanced power MOSFET. With low conduction loss, good switching performance and high avalanche energy, it is suitable for various power supply system, especially for AC step driving application for LED lighting.

The package type is SOT-223, which comply with the RoHS standard.

## **Key Parameters**

V <sub>DSS</sub>	600V
I <sub>D</sub>	1.5A
P <sub>D</sub> (T <sub>C</sub> = 25°C)	20W
R <sub>DS,ON,typ</sub>	7.0Ω

#### **FEATURES**

- Fast switching
- ESD improved capability
- Low gate charge (Typ. 7.5nC)
- Low reverse transfer capacitance (Typ. 5.0pF)

#### **APPLICATIONS**

- LED lighting applications
  - □ Downlight
  - □ High bay
  - □ Specialty
  - Architectural

#### **Equivalent Circuit**

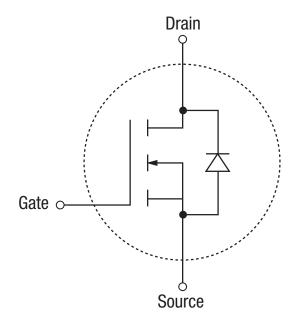
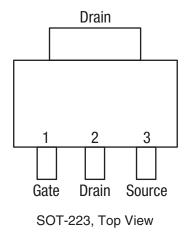


Figure 1. Equivalent Cirucit

### **Pin Configuration**



#### **Absolute Maximum Ratings**

Stresses beyond the limits listed below may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

 $T_C = 25^{\circ}C$  unless otherwise noted.

V <sub>DSS</sub> drain-to-source voltage	600V
$I_D$ continuous drain current ( $T_C = 25^{\circ}C$ )	1.5A
$I_D$ continuous drain current ( $T_C = 100^{\circ}C$ )	0.85A
I <sub>DM</sub> pulsed drain current	6A
V <sub>GS</sub> gate-to-source voltage	±30V
$P_D$ power dissipation ( $T_C = 25^{\circ}C$ )	20W
P <sub>D</sub> derating factor above 25°C	0.16W/°C
T <sub>STORAGE</sub> storage temperature range65	5°C to 150°C
E <sub>AS</sub> single pulse avalanche energy	80mJ
NOTE:	

Unless otherwise noted, all tests are pulsed tests at the specified temperature, therefore:  $T_J = T_C = T_A$ .

## **Operating Conditions**

T <sub>J</sub> operating junction temperature	150°C
T <sub>A</sub> operating ambient temperature40°C to	85°C



REV1B 2/6

## **Electrical Characteristics**

 $T_C = 25^{\circ}C$  unless otherwise noted.

Symbol	Parameter	Conditions	Min	Тур	Max	Units		
OFF Charac	cteristic							
$BV_{DSS}$	Drain to source breakdown voltage	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250μA				V		
$\Delta BV_{DSS}/\Delta T_{J}$	Breakdown voltage temperature coefficient	I <sub>D</sub> = 250μA, reference 25°C		0.71		V/°C		
I <sub>DSS</sub>		V <sub>DS</sub> = 600V, V <sub>GS</sub> = 0V, T <sub>A</sub> = 25°C			25	μΑ		
	Drain to source leakage current	V <sub>DS</sub> = 600V, V <sub>GS</sub> = 0V, T <sub>A</sub> = 125°C			250	μΑ		
I <sub>GSS(F)</sub>	Gate to source forward leakage	V <sub>GS</sub> = 30V			12			
I <sub>GSS(R)</sub>	Gate to source reverse leakage	V <sub>GS</sub> = -28V			-12	μΑ		
ON Charact	teristic (pulse width tp $\leq$ 380 $\mu$ s, $\delta \leq$ 2%)		•					
R <sub>DS(ON)</sub>	Drain to source on-resistance	$V_{GS} = 10V, I_D = 0.75A$		7.0	8.0	Ω		
V <sub>GS(TH)</sub>	Gate threshold voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.0		4.0	V		
Dynamic Characteristic								
9fs	Forward transconductance	$V_{DS} = 15V, I_D = 0.75A$		1.0		s		
C <sub>iss</sub>	Input capacitance			170		pF		
C <sub>oss</sub>	Output capacitance	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		27				
C <sub>rss</sub>	Reverse transfer capacitance			5				
Resistive Sv	witching Characteristic							
t <sub>d(ON)</sub>	Turn-on delay time			8				
t <sub>r</sub>	Rise time	$I_D = 1.5A, V_{DD} = 300V, V_{GS} = 10V,$		30		ns		
$t_{\text{d(OFF)}}$	Turn-off delay time	$R_G = 4.7\Omega$		22				
t <sub>f</sub>	Fall time			55				
Qg	Total gate charge			7.5				
Q <sub>gs</sub>	Gate to source charge	I <sub>D</sub> = 1.5A, V <sub>DD</sub> = 480V, V <sub>GS</sub> = 10V		1.7		nC		
Q <sub>gd</sub>	Gate to drain "Miller" charge			4.0		1		
Source-Drain Diode Characteristics (pulse width tp $\leq$ 380us, $\delta \leq$ 2%)								
Is	Continuous source current (body diode)				1.5	^		
I <sub>SM</sub>	Maximun source current (body diode)				6.0	Α		
V <sub>SD</sub>	Diode forward voltage	I <sub>S</sub> = 1.5A, V <sub>GS</sub> =0V			1.5	V		
T <sub>rr</sub>	Reverse recovery time			530		ns		
Q <sub>rr</sub>	Reverse recovery charge	$I_D = 1.5A$ , $T_J = 25$ °C, $dI_F/dt = 100A/\mu s$ , $V_{GS} = 0V$		1100		nC		
I <sub>RRM</sub>	Reverse recovery current			4.4		Α		



### **Typical Performance Characteristics**

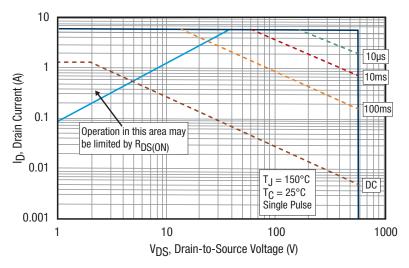


Figure 2. Safe Operating Area

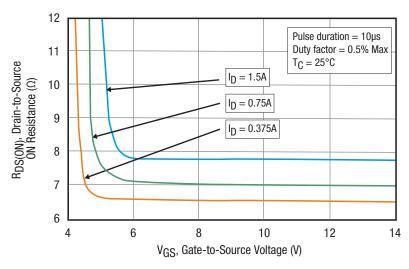


Figure 3. Typical Drain-to-Source ON Resistance vs. Gate Voltage and Drain Current

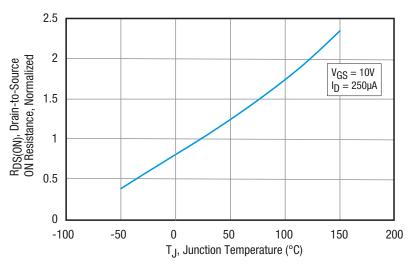
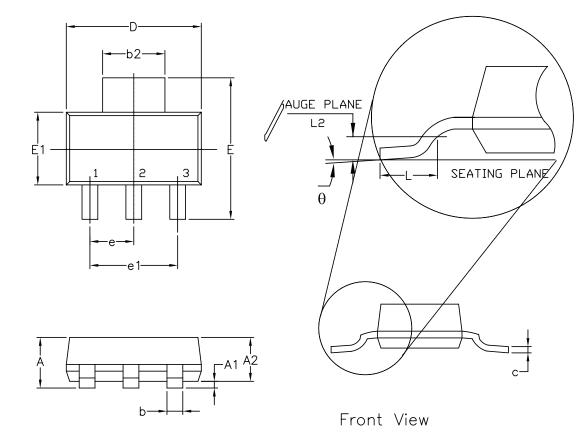


Figure 4. Typical Drain-to-Source ON Resistance vs. Junction Temperature



# **Package Description**

Top View



Side View

3 Pin SOT-223 JEDEC TO-261 Variation AA						
SYMBOLS	DIMENSIONS IN MM (Control Unit)			DIMENSIONS IN INCH (Reference Unit)		
	MIN	NOM	MAX	MIN	NOM	MAX
Α	_	_	1.80	_	_	0.071
A1	0.02	_	0.10	0.001	_	0.004
A2	1.50	1.60	1.70	0.060	0.063	0.067
b	0.66	0.76	0.84	0.026	0.030	0.033
b2	2.90	3.00	3.10	0.114	0.118	0.122
С	0.23	0.30	0.35	0.010	0.012	0.014
D	6.30	6.50	6.70	0.248	0.256	0.264
E	6.70	7.00	7.30	0.264	0.276	0.287
E1	3.30	3.50	3.70	0.130	0.138	0.146
е	2.30 BSC			C	.091 B	SC
e1	4.60 BSC		C	.182 B	SC	
L	0.75			0.030	ı	_
L2	0.25 BSC			0	.010 BS	SC C
θ	0°		10°	0°		10°
N	3				3	



#### Ordering Information(1)

Part Number	Operating Temperature Range	Package	Packaging Method	Lead Free <sup>(2)</sup>
XR46000ESETR	-40°C ≤ T <sub>J</sub> ≤ 150°C	SOT-223	Tape and reel	Yes

#### NOTES:

- 1. Refer to <a href="https://www.maxlinear.com/XR46000">www.maxlinear.com/XR46000</a> for most up-to-date Ordering Information.
- 2. Visit www.maxlinear.com for additional information on Environmental Rating.

#### **Revision History**

Revision	Date	Description
1A	Aug 2016	Initial release
1B	Nov 2019	Updated to MaxLinear logo. Updated Ordering Information.



5966 La Place Court Suite 100 Carlsbad, CA 92008 Tel.: +1 (760) 692-0711 Fax: +1 (760) 444-8598 www.maxlinear.com

The content of this document is furnished for informational use only, is subject to change without notice, and should not be construed as a commitment by MaxLinear, Inc. MaxLinear, Inc. assumes no responsibility or liability for any errors or inaccuracies that may appear in the informational content contained in this guide. Complying with all applicable copyright laws is the responsibility of the user. Without limiting the rights under copyright, no part of this document may be reproduced into, stored in, or introduced into a retrieval system, or transmitted in any form or by any means (electronic, mechanical, photocopying, recording, or otherwise), or for any purpose, without the express written permission of MaxLinear, Inc.

Maxlinear, Inc. does not recommend the use of any of its products in life support applications where the failure or malfunction of the product can reasonably be expected to cause failure of the life support system or to significantly affect its safety or effectiveness. Products are not authorized for use in such applications unless MaxLinear, Inc. receives, in writing, assurances to its satisfaction that: (a) the risk of injury or damage has been minimized; (b) the user assumes all such risks; (c) potential liability of MaxLinear, Inc. is adequately protected under the circumstances.

MaxLinear, Inc. may have patents, patent applications, trademarks, copyrights, or other intellectual property rights covering subject matter in this document. Except as expressly provided in any written license agreement from MaxLinear, Inc., the furnishing of this document does not give you any license to these patents, trademarks, copyrights, or other intellectual property.

MaxLinear, the MaxLinear logo, and any MaxLinear trademarks, MxL, Full-Spectrum Capture, FSC, G.now, AirPHY and the MaxLinear logo are all on the products sold, are all trademarks of MaxLinear, Inc. or one of MaxLinear's subsidiaries in the U.S.A. and other countries. All rights reserved. Other company trademarks and product names appearing herein are the property of their respective owners.

© 2016 - 2019 MaxLinear, Inc. All rights reserved.